ISSUED DATE :2005/04/14 REVISED DATE :2005/10/04B

GTM

GSS1120

Dual 1A Low Dropout Positive Regulator

Description

The GSC1120 series are low dropout positive regulator with minimum of 1A output current capability. The product is specifically designed to provide well-regulated supply for low voltage IC applications such as high speed bus termination and low current 3.3V/2.5V or 3.3V/1.8V logic supply. GSC1120 series and guaranteed to have <1.3V dropout at full load current making it ideal to provide well regulated outputs dual channels with up to 18V input supply.

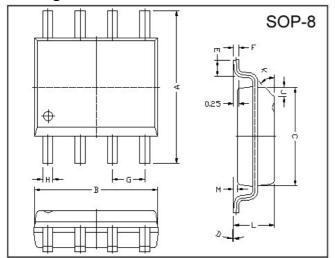
Features

- 1.3Vmaximum dropout at full load current
- Fast transient response
- Output current limiting for each channel
- Built-in thermal shutdown each channel
- · Good noise rejection
- Dual output A: ch1=3.3V, ch2=2.5V B: ch1=3.3V, ch2=1.8V

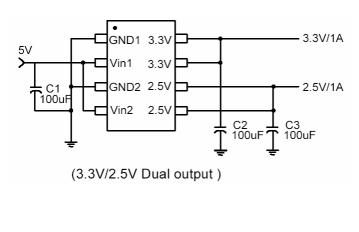
Applications

- PC peripheral
- Communication

Package Dimensions



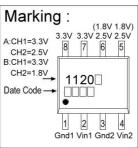
Typical Circuit



Pin Descriptions

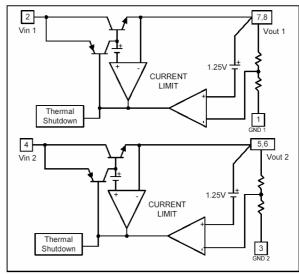
CORPORATION

| Name | Function |
|----------------------|--|
| GND 1/2 | Ground |
| 3.3V (Vout1) | The output of the regulator. A minimum of 10µF capacitor |
| 2.5V/1.8V (Vout2) | $(0.15\Omega \le \text{ESR} \le 20\Omega)$ must be connected from this pin to ground to insure stability. |
| Vin 1/2 | The input pin of regulator. Typical a large storage capacitor ($0.15\Omega \le ESR \le 20\Omega$) is connected form this pin to ground. |



| REF. | Millimeter | | REF. | Millimeter | | | |
|------|------------|------|-----------|------------|------|--|--|
| NEF. | Min. | Max. | lax. Min. | Max. | | | |
| Α | 5.80 | 6.20 | М | 0.10 | 0.25 | | |
| В | 4.80 | 5.00 | Н | 0.35 | 0.49 | | |
| С | 3.80 | 4.00 | L | 1.35 | 1.75 | | |
| D | 0° | 8° | J | 0.375 REF. | | | |
| E | 0.40 | 0.90 | K | 45° | | | |
| F | 0.19 | 0.25 | G | 1.27 TYP. | | | |

Block Diagram



Absolute Maximum Ratings

| Symbol | Parameter | Ratings | Unit |
|--------|--------------------------------------|--------------------|------|
| Vin | DC Supply Voltage | -0.3 to 12 | V |
| Pd | Power Dissipation | Internally Limited | |
| Tst | Storage Temperature | -65 ~ + 150 | °C |
| Тор | Operating Junction Temperature Range | 0 ~ + 150 | °C |

Electrical Characteristics

| Parameter | Conditions | | | Тур | Max | Unit |
|---|---|--|-------|----------|-------|------|
| Output Voltage | GSC1120A(B)-VOUT1 | lo=10mA, TJ=25℃, 4.8V≤ ViN ≤12V | 3.235 | 3.300 | 3.365 | V |
| | GSC1120A-VOUT2 | lo=10mA, TJ=25℃, 4.0V≤ ViN ≤12V | 2.450 | 2.500 | 2.550 | V |
| | GSC1120B-VOUT2 | lo=10mA, TJ=25℃, 4.0V≤ ViN ≤12V | 1.764 | 1.800 | 1.836 | V |
| Line Regulation | Io=10mA, Vout+1.5V< Vi≥ <12V, TJ=25℃ | | | - | 0.2 | % |
| Load Pogulation | GSC1120-VOUT1 | VIN=5V, 0mA <lo<1a, (note="" 1,2)<="" td="" tj="25°C"><td>-</td><td>26</td><td>33</td><td>mV</td></lo<1a,> | - | 26 | 33 | mV |
| Load Regulation | GSC1120-VOUT2 | VIN=4V, 0mA <lo<1a, (note="" 1,2)<="" td="" tj="25°C"><td>-</td><td>20</td><td>25</td><td>mV</td></lo<1a,> | - | 20 | 25 | mV |
| Dropout Voltage (VIN-VOUT) | Io=1Α, ΔVουτ=0.1%Voυτ | | - | 1.3 | 1.4 | V |
| Current Limit | VIN-VOUT=5V | | 1.1 | - | - | А |
| Minimum Load Current | 0°C≤ TJ ≤125°C (Note 3) | | - | 5 | 10 | mA |
| Thermal Regulation | Ta=25℃, 30ms pulse | | - | 0.008 | 0.04 | %/W |
| Ripple Rejection | F=120HZ, Cout=25uF Tantalum, lout=1A | | - | 60 | 70 | dB |
| Temperature Stability | lo=10mA | | | 0.5 | - | % |
| θJA Thermal Resistance Junction-to-Ambient(No heat sink ;No air flow) | SOP8: Control Circuitry/Power Transistor (Note 4) CH1 or CH2 only CH1 & CH2 and PD1=PD2 | | - | 50 45 | - | °C/w |
| θJC Thermal Resistance Junction-to-Case | SOP8: Control Circuitry/Power Transistor (Note 4) CH1 or CH2 only CH1 & CH2 and PD1=PD2 | | | 20 12 | - | °C/w |

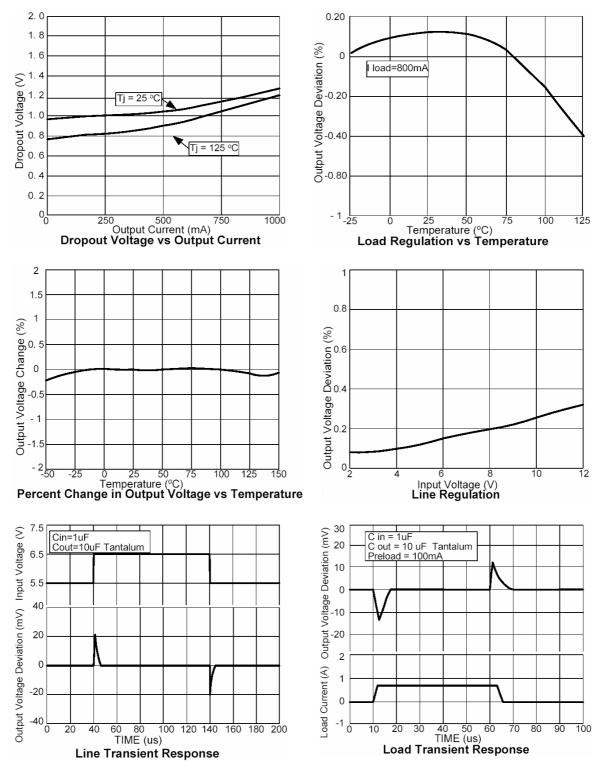
Note 1: See thermal regulation specifications for changes in output voltage due to heating effects. Line and load regulation are measured at a constant junction temperature by low duty cycle pulse testing. Load regulation is measured at the output lead =1/18" from the package.

Note 2: Line and load regulation are guaranteed up to the maximum power dissipation of 15W. Power dissipation is determined by the input/output differentially and the output current. Guaranteed maximum power dissipation will not be available over the full input/output range.

Note 3: Quiescent current is defined as the minimum output current that requires maintaining regulation. At 12V input/output differential the device is guaranteed to regulate if the output current is greater than 10mA.

Note 4: Vout1 and Vout2 are connected to the PCB cupper area 5.5mm*5.5mm separately. If you need large PD or lower Tc & TJ, please connect to the large cupper area >> 5.5mm*5.5mm (like 10mm*10mm).

Typical Performance Characteristics



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